

PH767DBR 767nm Series

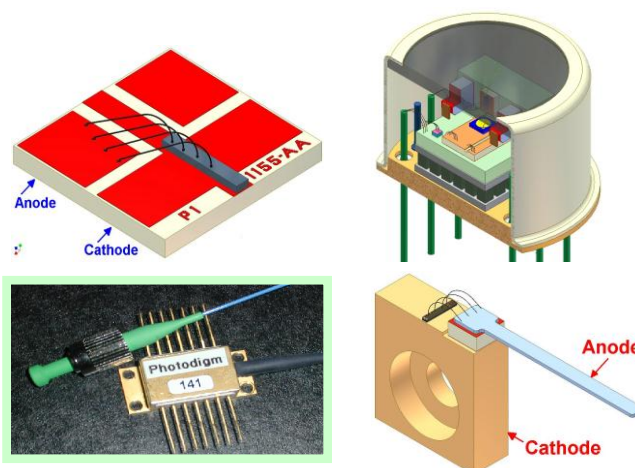
High-Power Single-Frequency Laser Diode

Technology

- DBR Single-Frequency Laser Chip
- AlGaAs QW Active Layer
- Epi designed for high reliability

Features

- Available in several package styles
- Pulsed operation for spectral stability at short pulse lengths
- High power for CW applications
- High Slope Efficiency



Description

The PH767DBR Series of high-power edge-emitting lasers are based on Photodigm's advanced single-frequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam. Facets are passivated for high-power reliability. Devices used for atomic spectroscopy applications.

Absolute Maximum Ratings

| Parameter | Symbol | Unit | Min | Max |
|---|------------|------|------|-------|
| Storage Temperature | T_{STG} | °C | 0 | 80 |
| Operating Temperature | T_{OP} | °C | 5.0 | 70 |
| CW Laser Forward Current, $T=T_{op}$ | I_F | mA | - | 150** |
| Pulsed Laser Forward Current, $T=25^{\circ}\text{C}$, PW=300 ns, DC=10% | I_F | A | - | 0.3 |
| Laser Reverse Voltage | V_R | V | - | 0.0 |
| Photodiode Forward Current <u>1/2/</u> | I_P | mA | - | 5.0 |
| Photodiode Reverse Voltage <u>1/2/</u> | V_R | V | - | 20.0 |
| Photodiode Dark Current, $V_R=10\text{V}$, LD $I_F=0$, <u>1/2/</u> | I_D | nA | - | 50 |
| TEC Current <u>1/2/</u> | I_{TEC} | A | -2.0 | 2.0 |
| TEC Voltage <u>1/2/</u> | V_{TEC} | V | -6.0 | 6.0 |
| Thermistor Current <u>1/2/</u> | I_{THRM} | mA | - | 1.0 |
| Thermistor Voltage <u>1/2/</u> | V_{THRM} | V | - | 10 |
| External Back Reflection | - | dB | - | -14 |
| Lead Soldering Temperature, 10 sec. Max. <u>1/2/</u> | - | °C | - | 260 |
| Fiber Pull Force <u>1/</u> | - | N | - | 5.0 |
| Fiber Bend Radius <u>1/</u> | - | mm | - | 35 |

1/ Butterfly package 2/ TO8 package** Do not exceed drive current or operating power of supplied LIV**

CW Characteristics at T_c = 25°C unless otherwise specified

| Parameter | Symbol | Unit | Min | Typ | Max |
|--|-------------------------------------|------------|----------------------------|--------|--------|
| Center Wavelength | λ_c | nm | 765 | 767 | 769 |
| Optical Output Power @ LIV Current | P _o | mW | See Power Options Call-out | | |
| Slope Efficiency, 1/ | η_d | W/A | 0.25 | 0.36 | |
| Slope Efficiency | η_d | W/A | 0.60 | 0.75 | - |
| Threshold Current | I _{th} | mA | - | 50 | 70 |
| Laser Series Resistance | R _S | Ω | - | 2.0 | 2.5 |
| Laser Forward Voltage | V _F | V | - | 2.0 | 2.5 |
| Thermistor Resistance @ 25°C, 1/2/ | R _T | K Ω | - | 10 | - |
| Photodiode Dark Current, V _R =10V, LD I _F =0, 1/2/ | I _D | nA | - | - | 50 |
| Laser Line Width | $\Delta\nu$ | MHz | - | 0.7 | 1.0 |
| Polarization Extinction Ratio, 1/ | PER | dB | -16 | -19 | - |
| Beam Divergence @ FWHM | $\theta_{ } \times \theta_{\perp}$ | $^{\circ}$ | - | 6 X 26 | 8 X 28 |
| Side Mode Suppression Ratio | SMSR | dB | -30 | - | - |
| Laser Polarization | | | | TE | |
| Mode Structure | | | Fundamental Mode | | |

1/ Butterfly package 2/ TO-8 package

Handling Precautions

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.

How To Order

Part number example: PH767DBR040CM. Assign optical power from those shown below. Use a three-digit format for all power entries. Call factory for special performance selection and certification to certain atomic absorption lines. Butterfly package is offered at 20mW operating power only and is not recommended for Spectroscopy applications. See Photodigm's application note titled "Optical Feedback".

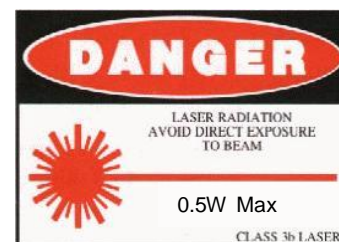
PH767DBR 

Operating Power
(mW)

020
040
080

Package Type

CS Chip on Submount
CM 'C' Mount
BF Butterfly
T8 TO-8



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